## Transmissive Optical Sensor with Phototransistor Output

## Description

The TCST1230 is a transmissive sensor that includes an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light.

## Features

- Package type: Leaded
- Detector type: Phototransistor
- Dimensions:

L $9.2 \mathrm{~mm} \times \mathrm{W} 4.8 \mathrm{~mm} \times \mathrm{H} 5.4 \mathrm{~mm}$


## Applications

- Optical switch
- Shaft encoder
- Detection of opaque material such as paper
- Detection of magnetic tapes
- Lead (Pb)-free soldering released
- Lead ( Pb )-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC
- Minimum order quantity: 4800 pcs, 60 pcs/tube


## Absolute Maximum Ratings

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified

## Coupler

| Parameter | Test condition | Symbol | Value | Unit |
| :--- | :--- | :---: | :---: | :---: |
| Total power dissipation | $\mathrm{T}_{\mathrm{amb}} \leq 25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\text {tot }}$ | 250 | mW |
| Operation temperature range |  | $\mathrm{T}_{\mathrm{amb}}$ | -25 to +85 |  |
| Storage temperature range |  | $\mathrm{T}_{\text {stg }}$ | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| Soldering temperature | Distance to package 1.6 mm, <br> $\mathrm{t} \leq 5 \mathrm{~s}$ | $\mathrm{~T}_{\mathrm{sd}}$ | ${ }^{\circ} \mathrm{C}$ |  |

## Input (Emitter)

| Parameter | Test condition | Symbol | Value | Unit |
| :--- | :--- | :---: | :---: | :---: |
| Reverse voltage |  | $\mathrm{V}_{\mathrm{R}}$ | 6 | V |
| Forward current |  | $\mathrm{I}_{\mathrm{F}}$ | 60 | mA |
| Forward surge current | $\mathrm{t}_{\mathrm{p}} \leq 10 \mu \mathrm{~A}$ | $\mathrm{I}_{\mathrm{FSM}}$ | 3 | A |
| Power dissipation | $\mathrm{T}_{\mathrm{amb}} \leq 25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{V}}$ | 100 | mW |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 100 | ${ }^{\circ} \mathrm{C}$ |

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Output (Detector)

| Parameter | Test condition | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Collector emitter voltage |  | $\mathrm{V}_{\text {CEO }}$ | 70 | V |
| Emitter collector voltage |  | $\mathrm{V}_{\text {ECO }}$ | 7 | V |
| Collector current |  | $\mathrm{I}_{\mathrm{C}}$ | 100 | mA |
| Power dissipation | $\mathrm{T}_{\mathrm{amb}} \leq 25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{V}}$ | 150 | mW |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 100 | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified

## Coupler

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector current | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ | $\mathrm{I}_{\mathrm{C}}$ | 0.5 |  | 14 | mA |
| Collector emitter saturation <br> voltage | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=0.2 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{CEsat}}$ |  |  | 0.4 | V |

Input (Emitter)

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Forward voltage | $\mathrm{I}_{\mathrm{F}}=60 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{F}}$ |  | 1.25 | 1.5 | V |
| Junction capacitance | $\mathrm{V}_{\mathrm{R}}=0, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\mathrm{j}}$ |  | 50 |  | pF |

Output (Detector)

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Collector emitter voltage | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ | $\mathrm{~V}_{\mathrm{CEO}}$ | 70 |  | V |  |
| Emitter collector voltage | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{ECO}}$ | 7 |  | V |  |
| Collector dark current | $\mathrm{V}_{\mathrm{CE}}=25 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \mathrm{E}=0$ | $\mathrm{I}_{\mathrm{CEO}}$ |  | 10 | 100 | nA |

## Switching Characteristics

| Parameter | Test condition | Symbol | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Turn-on time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=100 \Omega \text { (see figure } 1 \text { ) } \end{aligned}$ | $\mathrm{t}_{\text {on }}$ |  | 15.0 |  | $\mu \mathrm{s}$ |
| Turn-off time | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \\ & \left.\mathrm{R}_{\mathrm{L}}=100 \Omega \text { (see figure } 1\right) \end{aligned}$ | $\mathrm{t}_{\text {off }}$ |  | 10.0 |  | $\mu \mathrm{s}$ |



Figure 1. Test Circuit for $t_{\text {on }}$ and $t_{\text {off }}$


Figure 2. Switching Times

## Typical Characteristics

$\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified


Figure 4. Forward Current vs. Forward Voltage


Figure 3. Power Dissipation Limit vs. Ambient Temperature


Figure 5. Relative Current Transfer Ratio vs. Ambient Temperature

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Figure 6. Collector Dark Current vs. Ambient Temperature


Figure 7. Collector Current vs. Forward Current


Figure 8. Collector Current vs. Collector Emitter Voltage


Figure 9. Current Transfer Ratio vs. Forward Current


Figure 10. Turn on/off Time vs. Collector Current


Figure 11. Relative Collector Current vs. Displacement

## Package Dimensions in mm



Drawing-No.: 6.550-5123.01-4
Issue: 5; 30.01.06
9612083

## Tube Dimensions



With rubber stopper
Tolerance: $\pm 0.5 \mathrm{~mm}$
Length: $575 \pm 1 \mathrm{~mm}$
All dimensions in mm
Drawing-No:: 9.700-5245.01-4
Issue: 1; 25.02.00
20256

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